



HAL
open science

Size effects in the deformation of sub-micron Au columns

Cynthia Ann Volkert, Erica T Lilleodden

► **To cite this version:**

Cynthia Ann Volkert, Erica T Lilleodden. Size effects in the deformation of sub-micron Au columns. *Philosophical Magazine*, 2006, 86 (33-35), pp.5567-5579. 10.1080/14786430600567739. hal-00513658

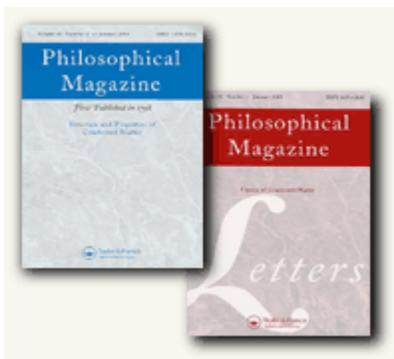
HAL Id: hal-00513658

<https://hal.science/hal-00513658>

Submitted on 1 Sep 2010

HAL is a multi-disciplinary open access archive for the deposit and dissemination of scientific research documents, whether they are published or not. The documents may come from teaching and research institutions in France or abroad, or from public or private research centers.

L'archive ouverte pluridisciplinaire **HAL**, est destinée au dépôt et à la diffusion de documents scientifiques de niveau recherche, publiés ou non, émanant des établissements d'enseignement et de recherche français ou étrangers, des laboratoires publics ou privés.



Size effects in the deformation of sub-micron Au columns

Journal:	<i>Philosophical Magazine & Philosophical Magazine Letters</i>
Manuscript ID:	TPHM-05-Nov-0491.R1
Journal Selection:	Philosophical Magazine
Date Submitted by the Author:	15-Dec-2005
Complete List of Authors:	Volkert, Cynthia; Forschungszentrum Karlsruhe Lilleodden, Erica; Forschungszentrum Karlsruhe
Keywords:	plasticity of metals, compression, dislocation mechanics, focused ion beam, metals, nanomechanics
Keywords (user supplied):	



Size effects in the deformation of sub-micron Au columns

C. A. VOLKERT* and E. T. LILLEODDEN

Institut für Materialforschung II

Forschungszentrum Karlsruhe

Karlsruhe, Germany

Uniaxial compression tests have been performed on single crystal Au columns ranging in diameter from 180 nm to 8 μm . The columns were machined into the surface of a large-grained Au sheet using a focused ion beam microscope and then mechanically tested using a nanoindenter outfitted with a flat diamond punch. Images of the compressed columns show that deformation occurs by localized shear on the slip systems with the largest resolved shear stresses. After an elastic loading regime, the columns exhibit yielding in discrete strain bursts. The compressive yield stress scales roughly as the inverse square root of the column diameter. The apparent strain hardening rate also increases strongly with decreasing column diameter and stresses as large as 1 GPa are reached. Both of these size effects are attributed to dislocation source-limited behaviour in small volumes.

Keywords: Compression; Nanomechanics; Dislocation mechanics; Focused ion beam; Metals; Plasticity of metals

1. INTRODUCTION

Size effects in the mechanical behaviour of metals are of interest because of the fundamental insight they provide into dislocation mechanisms and because of their technological relevance. Metal components with sub-micron dimensions are used in many technological applications (e.g. microelectronic devices, micro-electro-mechanical devices, and nanoimprinting stamps) where mechanical integrity and reliability are paramount. For sample sizes smaller than the dislocation cell size or dislocation interaction distance ($\sim 5 \mu\text{m}$) sample surface effects become very important. The importance of surfaces in deformation behaviour has been recognized for decades and has motivated studies on Au [1-3], which has no native oxide. Free surfaces can serve as effective sinks and sources for dislocations, and can inhibit dislocation storage within the deforming volume. Therefore, as sample dimensions become smaller the role of surfaces become more important, and can lead to interesting and unusual mechanical behaviour.

Nanoindentation is a useful technique for studying size effects in materials due to the ease of varying the deformation length-scale and the high resolution load-displacement data that is obtained. In the smallest depth regime, discrete displacement bursts, so called “pop-ins” [1,4-6], have often been observed and associated with dislocation nucleation events. At larger length scales, depth-dependent hardness is observed and is often described as a strain gradient effect [7]. However, the complicated, inhomogeneous strain field imposed during indentation renders such data difficult to interpret. Sample size effects have also been studied in thin film systems, where the thickness of the film is the critical length-scale. In addition to their technological relevance, the attractiveness of studying thin films is the ease of sample preparation. However, since grain size often scales with the film thickness, separating microstructure effects from sample size effects is complicated. Furthermore, for films on substrates, the substrate is inherently involved in the mechanical behaviour and where temperature changes are used to load the film, such as for wafer curvature experiments, the thermal and mechanical effects are combined. In the case of free-standing films, problems with limited ductility, buckling and tearing are often encountered.

1
2
3
4
5
6
7
8
9
10
11
12
13
14
15
16
17
18
19
20
21
22
23
24
25
26
27
28
29
30
31
32
33
34
35
36
37
38
39
40
41
42
43
44
45
46
47
48
49
50
51
52
53
54
55
56
57
58
59
60

Recently, a new approach to investigating sample size effects has been introduced [8-10]. Focused ion beam (FIB) fabrication is used to make novel micro-mechanical test specimens which can then be tested using high resolution loading such as with a nanoindenter. One particularly simple and elegant experiment involves uniaxial compression of FIB-machined columns using a nanoindenter outfitted with a flat punch. The simple loading state can be used to circumvent the strain gradients inherent in conventional indentation experiments, while still allowing isothermal, small-volume investigations. Furthermore, the fabrication of micro-columns in the surface of samples by FIB is relatively easy, site-specific, and can be applied to a wide range of materials. Since the methodology was first used to study size effects in single crystal Ni and Ni alloys [8-10], the method has been applied to $\langle 100 \rangle$ oriented single crystal Au [11] and in our lab to a whole range of materials such as single crystal metals (Au, Al, Cu, and Ta), multilayer films, and amorphous, nanocrystalline, and nanoporous metals.

In this paper, the compressive stress-strain behaviour of micron and sub-micron columns of single crystal Au is investigated. Using the microcompression testing method on FIB fabricated columns of varying diameter and orientation, the effect of sample size on the mechanical behaviour under uniform stresses has been systematically studied. This work goes beyond previous micro-compression work on Au [11] in that we have studied different crystallographic orientations and have achieved reliable measurements of the yield stresses in columns with diameters below 500 nm [12]. In addition to investigating size effects on the yield stress and hardening behaviour, the identification of active slip systems via post-deformation microscopy has been conducted. A new dislocation source-limited model is proposed to explain the observed inverse square root dependence of the yield stress on column diameter and the strong increase in hardening with decreasing diameter.

2. EXPERIMENTAL PROCEDURE

Gold foil with a purity of 99.999% and thickness of 100 μm was obtained in the as-rolled condition. Small pieces (3 mm by 3 mm) were mechanically polished and then annealed in vacuum at 800°C for 24 hours to allow for grain growth. The annealed foil was mounted on a SEM sample stub where it remained for all subsequent investigations. Particular care was taken when gluing the sample to the holder to avoid deformation and the introduction of dislocations in the foil. Focused ion beam (FIB) microscopy of the annealed foil revealed equiaxed grains ranging in size from 50 to 200 μm and containing occasional twin boundaries.

Three large grains (Grains A, B, and C) were selected for column preparation. The crystallographic orientations of the grains were measured using electron back-scatter diffraction and the out-of-plane orientations are described by the direction cosines h , k , and l in table 1. They all have low symmetry orientations and fall well away from the boundaries of the standard orientation triangle. This means they are expected to deform by single slip during loading in the out-of-plane direction. Crystallographic information about the three grains is given in table 1, including the Young's moduli, and the Schmid factors and inclinations relative to the compression axis for the slip systems with the maximum resolved shear stresses.

The 30 keV Ga beam in the FIB was used to mill columns in the surface of the selected grains. The fabrication of well-defined columns with vertical sidewalls is complicated by a number of details of the ion sputtering process, namely, the finite diameter and tails of the ion beam, the angular dependence of the sputter yield, ion reflection, and redeposition. A relatively fast, two step milling method was developed to produce columns in about one hour with an approximate cylindrical geometry, as shown in figure 1. This optimised process involved first milling a ring with an outer diameter of 30 μm and an inner diameter several microns larger than the desired column diameter, to a depth close to the

1
2
3 desired column height. The 30 μm outer diameter is necessary to leave sufficient space for the
4 10 μm diameter punch that is used for mechanically testing the columns. In the second step of
5 the milling process, a sequence of “single-pass” rings with ever decreasing radii were used to
6 decrease the diameter of the column to the desired value. This single-pass mode results in
7 higher sputter yields and also avoids re-deposition on the side walls of the column. From our
8 experience, short of resorting to the effective but more time-intensive “ion lathe” method [8-
9 10], this is the best method to minimize taper of the column walls and rounding of the top and
10 bottom edges of the column. The geometry of the column is critical to analysing compression
11 data, and is easily obtained from SEM imaging. The column height, h , is defined as the
12 vertical distance between the extrapolated intersections of the inclined walls with the column
13 top and with the underlying material (illustrated in figure 1). The column diameter, d , is
14 defined as the diameter at half the column height. Final column diameters ranged from 180
15 nm to 8 μm and heights from 500 nm to 11 μm . The aspect ratios of the columns were chosen
16 between 1.5 and 4. Below 1.5, there is danger that slip may be hindered by the underlying
17 material. Above an aspect ratio of 4, plastic buckling of the columns becomes a problem. A
18 constant aspect ratio also ensures a constant fractional contribution from constraints at the
19 column ends and from the compliance of the underlying material [13].

20
21 The columns were compressed in an MTS XP Nanoindenter using a flat diamond
22 punch. The punch is a 60° conical indenter that has been truncated to form a 10 μm diameter
23 circular flat (Synton, Switzerland). A typical experiment consisted of compressing the column
24 at a fixed loading rate (between 0.8 and 100 $\mu\text{N/s}$) to a prescribed maximum displacement,
25 followed by a hold-load segment prior to unloading.

26
27 The stress and strain in the column is determined using the measured force on the
28 column F and the measured displacement Δx_{meas} into the sample surface. Given the fact that
29 deformation often occurred inhomogeneously by single or double slip, determination of the
30 true stresses and strains was not attempted and the engineering stresses $\sigma = 4F/\pi d^2$ and
31 engineering strains $\varepsilon = \Delta x/h$ of the columns were used instead. However, an important
32 correction to the displacement data due to the compliance of the underlying material is needed
33 [13,14]. Assuming that the displacement profile of the material under the column can be
34 approximated by the displacement profile due to pushing a rigid punch into the surface, the
35 relation between the column displacement Δx and the measured displacement Δx_{meas} is [14],

$$\Delta x = \Delta x_{meas} / (1 + (\pi/4)(1-\nu^2)(d/h))$$

36
37 where ν is the Poisson ratio of the underlying material (0.44 for polycrystalline Au) and h/d is
38 the column aspect ratio. For the smallest column aspect ratio of 1.5 the contribution to the
39 measured displacement from the underlying material ($1-\Delta x/\Delta x_{meas}$) can be as large as 30%.
40 This correction does not account for possible plasticity in the underlying material, which can
41 lead to apparent decreases in the measured stresses and increases in the plastic strain.
42 However, we do not believe that plasticity in the underlying material is a major issue since the
43 total plastic strain measured with the nanoindenter (after unloading) is consistent with the
44 total change in column height observed in the SEM, to within several percent strain. Other
45 known inaccuracies in the engineering stress and strain calculated as described above come
46 from deviations in the column geometry from a perfect cylindrical column (e.g., column
47 taper), possible friction between the diamond punch and the column top, and constraint of the
48 column by the underlying material [13]. For the column shapes used here, these effects are
49 deemed negligible in comparison with the assumptions associated with using the engineering
50 stress and strain.

51
52 Following compression, the deformed columns were imaged by SEM. In addition to
53 qualifying the type of slip that occurred (e.g., single or multiple slip) and identifying the
54 active slip systems, SEM imaging allows verification that the column was contacted and not

1
2
3 the surrounding material. Although it was not always apparent from the stress-strain curves,
4 SEM images showed that some of the columns deformed by plastic buckling; these columns
5 were not considered in subsequent analysis.
6
7

8 3. EXPERIMENTAL RESULTS 9

10 An engineering stress-strain curve is shown in figure 2 from a 710 nm diameter column with
11 an initial height of 1.75 μm . The column deformed by single slip as evidenced by the post-
12 compression SEM image in the inset of the figure. The inclination of the slip plane to the load
13 axis can be estimated as 52° which is the predicted inclination for the active slip system in
14 this grain (table 1). The steep increase in stress at the beginning of the loading cycle is due to
15 elastic loading in combination with “early plasticity” effects. Such micro-plasticity is likely
16 due to surface roughness and initial seating of the punch on the top of the column; perfect
17 planarity between the punch and the column is not achievable. At larger strains, the column
18 deforms plastically in discrete strain bursts separated by almost elastic loading intervals. At
19 the maximum depth of 400 nm, the measured load is held fixed for 15 s. The beginning of the
20 hold is indicated by an arrow in figure 3 during which time one percent plastic strain occurs.
21 The slope of the first part of the unloading curve is 109 GPa, which is larger than the
22 calculated value of the Youngs modulus for this orientation (table 1). This presumably has to
23 do with the change in column geometry due to deformation. Estimating the deformed column
24 geometry from the image in figure 2 (1.6 μm height, 800 nm diameter), the corrected Youngs
25 modulus becomes 79 GPa, which is very close to the expected value (table 1).
26
27

28 Here we define the yield stress for the columns as the stress at 5% plastic strain since
29 the usual definition of yield stress at 0.2% plastic strain is difficult to apply to these
30 experiments due to early plasticity. By selecting a plastic strain of 5%, one can minimize
31 errors due to early plasticity while still avoiding extensive strain hardening effects in the yield
32 stress. The amount of strain hardening is estimated from the slope of the data between 5 and
33 15 % plastic strain or until the end of the loading curve. For the 710 nm column, the yield
34 stress is 154 MPa and the strain hardening coefficient is 472 MPa.
35
36

37 Representative stress-strain curves for columns with different diameters are shown in
38 figure 3. Both the yield stress and the strain hardening coefficient increase with decreasing
39 column diameter. SEM images of the deformed columns are shown in figure 4. Single slip
40 (figure 4(c) and (f)) and multiple slip (figure 4(a), (b), (d), and (e)) are seen. In some cases
41 deformation is localized in a few narrow slip bands (figure 4(c) and (f)), in other cases
42 numerous slip bands are formed (figure 4(a) and (b)). The column in figure 4(e) shows an
43 example of homogenous duplex slip followed by localized single slip on a third system. The
44 number of active slip systems did not depend on column diameter but did depend on the
45 crystallographic orientation: most of the columns fabricated within Grain A deformed by
46 double or triple slip, most of the columns fabricated within Grain B deformed by single slip,
47 and all of the columns fabricated within Grain C exhibited double or triple slip. This is
48 consistent with the resolved shear stresses. The primary slip systems have a Schmid factor of
49 0.48 in all grains. The second highest Schmid factor is 0.44 in Grain A, 0.40 in Grain C, and
50 0.38 in Grain B. In all grains, estimates of the inclinations of the slip planes from the images
51 are consistent with slip occurring on the systems with the highest resolved shear stresses.
52
53

54 To illustrate the extent of the reproducibility of the stress-strain behaviour, the loading
55 data from six 300 nm diameter columns are shown in figure 5. Allowing for early plasticity
56 and the stochastic nature of the strain bursts, the curves agree quite well. Additionally, strain
57 rate sensitivity was not observed; columns tested at different loading rates showed nominally
58 the same stress-strain response. The deformed columns corresponding to the curves labelled
59 (a) – (c) in figure 5 are shown in figure 6. The columns from Grain A (figure 6(a) and (b))
60 show very localized slip on one slip system and more homogeneous slip on a second system.

1
2
3 Column (b) deforms at a larger stress than column (a) and along a slip system at the bottom of
4 the column with a longer slip path. The slip geometry of the column from Grain C (figure
5 6(c)) is probably localized single slip although it is difficult to see due to the presence of a
6 partially decohered and burst surface film. This surface film is believed to be a carbon-based
7 layer that forms during SEM imaging of the Au columns prior to mechanical testing and that
8 typically bursts or delaminates during testing. In larger columns where smaller electron beam
9 fluences are needed for imaging or in columns that were imaged with the ion beam no
10 evidence of a surface layer was found. For this reason, it is concluded that the approximately
11 20 nm thick layer is carbon-based and is deposited during electron beam imaging. No
12 difference was observed between the mechanical behaviour of columns with and without the
13 carbonaceous layer (e.g. figure 5).

14
15
16 The yield stresses and the strain hardening rates are summarized in log-log plots in
17 figure 7 for all of the columns tested. Both quantities increase strongly as the column diameter
18 is decreased from 8 μm to 180 nm. No obvious differences are observed between the yield
19 stresses and strain hardening rates for the different grain orientations, revealing that the stress-
20 strain behaviour does not depend strongly on whether single or multiple slip occurs.

21 22 23 4. DISCUSSION 24

25
26 A systematic investigation of the stress-strain behaviour and deformation morphology of
27 small Au columns under uniaxial compression has been performed. It is observed that plastic
28 deformation occurs largely by discrete strain bursts associated with dislocation glide on the
29 slip systems with the maximum resolved shear stresses. The resultant stress-strain behaviour
30 does not depend on whether single or multiple slip occurs or whether it is localized or
31 homogeneous. This somewhat surprising result can be rationalized by the easy egression of
32 dislocations through the surfaces of the smaller columns; dislocation storage is insignificant,
33 therefore the typical hardening response from secondary slip is not observed.

34
35 Discrete strain bursts during homogeneous loading were first observed in Ni and Ni
36 alloy columns [8-10] and have also been reported in $\langle 100 \rangle$ Au columns [11]. They are similar
37 in concept but larger than the strain bursts observed during inhomogeneous loading by
38 nanoindentation of a wide range of metals [15]. Presumably, the strain bursts are due to a
39 plastic instability or self-organized critical behaviour [15], where the motion of a few
40 individual dislocation sets off an avalanche of dislocation nucleation and glide events. For
41 example, the motion of roughly 400 edge dislocations to the sample surface within less than
42 one second would be required to explain the strain bursts observed in the 710 nm diameter
43 column in figure 2. The magnitude of this effect is certainly enhanced by the load control used
44 in these experiments since the stress is held almost constant during such a burst. While the
45 load control testing procedure influences the strain bursts it is not believed to be the origin of
46 the effect.

47
48
49 A best fit to the yield stress data (figure 7(a)) gives $\sigma_y \sim d^{-0.61}$ which is close to the
50 inverse square root dependence typically observed for the effect of grain size on yield stress
51 (e.g., the Hall-Petch relation). In the largest columns, yield stresses as small as 50 MPa are
52 measured, falling between the values for the yield stress of well-annealed (~ 2 MPa [16]) and
53 severely worked (205 MPa [17]) bulk, single crystal Au. In the smallest column (180 nm
54 diameter), a yield stress of 560 MPa is reached. The data measured here agree well with
55 polycrystalline Au film data obtained at much lower strains by wafer curvature measurements
56 during thermal cycling [2] (shown in figure 7(a)) and with previous data for $\langle 100 \rangle$ Au
57 columns with diameters above 500 nm [11]. In contrast, the tremendously large yield stresses
58 measured by Greer et al. [11] in $\langle 100 \rangle$ oriented Au columns with diameters smaller than 500
59 nm are not observed here. It has since been acknowledged [12] that these high yield stresses
60 were not accurately analysed.

1
2
3 The strain hardening rate (figure 7(b)) is best described by the relation $E_h \sim d^{-1.07}$. The
4 rate determined using the “true” stresses and strains (defined as the instantaneous stress and
5 strain assuming homogeneous deformation and volume conservation) will certainly be lower
6 than that for the equivalent engineering stress and strain response used here. However, due to
7 the inhomogeneous nature of the deformation in most of the columns tested here, estimates of
8 the strain hardening rate based on the true stress and strain are not expected to be any more
9 accurate than those based on the engineering stresses and strains. For instance, localized
10 plasticity on a single slip plane would lead to a reduction in the cross sectional area, rather
11 than an increase as would be predicted from a volume conservation assumption used in true
12 stress-strain analyses [11]. In addition, although a more accurate determination of the stresses
13 and strains might lead to lower values of the strain hardening rate, it will not eliminate the
14 very strong effect of column diameter. The strain hardening rate in the largest columns is
15 roughly 100 MPa which agrees very well with the values for hardening in bulk metals. In the
16 smallest columns, the large strain hardening rates of 5 GPa result in stresses close to the
17 theoretical strength (roughly 2 GPa for Au of this orientation [18]) being reached. The column
18 that showed the largest stress of 1 GPa (figure 6(b)) exhibited homogeneous slip on one slip
19 system followed by very localized slip at the base of the column on a second slip system. In
20 order to reach the large stresses necessary to activate this second slip system, the sources on
21 the first system must have been depleted.

22
23 Three different mechanistic scenarios are discussed to account for the observed
24 dependence of the yield stress and strain hardening rate on column diameter. These are: (1)
25 Taylor hardening by dislocation interactions, (2) the presence of a surface layer that acts as a
26 barrier to dislocation motion, and (3) dislocation source-limited behaviour.

27
28 (1) The classic explanation for an increase in yield stress is through an increase in
29 dislocation density (Taylor hardening). As the dislocation density is increased, the stress
30 required to move a dislocation through a field of dislocations is also increased. However, to
31 reach the measured stresses of more than 1 GPa, a dislocation density of $10^{16}/\text{m}^2$ is required
32 (dislocation spacing of 10 nm). Such high dislocation densities are only observed in
33 deformation cell walls and are not expected to be reached here. In addition, the observed yield
34 stress dependence on the column diameter would require that the dislocation density scale as
35 the inverse of the diameter. This is often predicted for sample volumes with blocking
36 boundaries [19-21]. However such a situation is hard to envision if the dislocations are free to
37 leave through the surface. In fact a recent two-dimensional simulation of the dislocation
38 density in small compression specimens with free surfaces predicts that the dislocation
39 density scales directly as the square root of the sample diameter [22]. With or without a
40 blocking surface layer, it is hard to envision reaching the high dislocation densities necessary
41 to explain the large measured stresses by Taylor hardening.

42
43 (2) It is usually assumed that the Au surface is oxide-free and that dislocations can
44 easily leave the crystal helped by image forces. The surface carbonaceous film associated
45 with electron beam imaging discussed earlier does not influence the stress-strain behaviour
46 and presumably does not hinder dislocation motion. However in the columns studied here,
47 fabrication by Ga ion beam sputtering will result in a heavily damaged, implanted layer at the
48 side walls of the columns. Based on Monte Carlo simulations [23] of 30 keV Ga sputtering of
49 Au at a glancing angle of 2° , both ion beam damage and several atomic percent of Ga are
50 expected in the outer 15 nm of the sample. If the layer is sufficiently strong and stiff to block
51 the egress of dislocations from the sample, then deformation is expected to occur by the
52 nucleation and pile up of dislocations in the Au column until stresses are reached that are
53 large enough to break through the alloy surface layer. By analogy with the mechanism
54 proposed for the Hall-Petch relation in polycrystalline samples, as well as based on discrete
55 dislocation simulations of dislocation nucleation in bounded volumes [24], it is expected that
56 a blocking surface layer will lead to an inverse square root dependence of the yield stress on
57
58
59
60

1
2
3 the column diameter, consistent with the observations presented here. Under certain
4 circumstances, blocking boundaries can also lead to a significant increase in strain hardening
5 with decreasing sample size [19]. However, although the presence of a hard surface layer is
6 consistent with the results presented here, it is unlikely that the Ga-implanted layer can
7 support such large stresses or that sufficiently high dislocation densities can be reached, as
8 discussed in point (1).
9

10 (3) A third and more convincing rationale for the observed size dependence can be
11 found in dislocation source-limited behaviour. Following the framework of the Hall-Petch
12 relation, a large dislocation density (such as in a dislocation pile-up) leads to large internal
13 stresses which can activate dislocation sources. Since the dislocation density is expected to be
14 lower in the small columns due to the loss of dislocations through the sample surface, the
15 applied stress required to nucleate or activate dislocation sources can be argued to decrease
16 with increasing column diameter. Thus, large columns will have a high dislocation density
17 and will readily reach the local stresses required to nucleate or activate sources. In contrast,
18 the small columns will have a lower dislocation density and will require applied stresses
19 closer to the theoretical source strength to deform. According to Hall-Petch considerations as
20 well as discrete dislocation simulations [22], this will lead to an inverse square root
21 dependence of the yield stress on the column diameter, as is observed. As plasticity continues,
22 the dislocation density is further reduced by dislocations leaving the crystal through the
23 surface, which happens preferentially in the smallest columns. This in turn requires an
24 increase in applied stress to activate new sources. This hardening mechanism is therefore due
25 to a *decrease* in dislocation density rather than an *increase* as described by the conventional
26 Taylor model. Thus, the dislocation source-limited model is able to qualitatively account for
27 the dependence of the yield stress on column diameter and the increase in strain hardening
28 with decreasing column diameter.
29
30
31
32
33

34 5. CONCLUSIONS

35
36 We have performed compression tests on micron and sub-micron single crystal Au columns.
37 Plastic deformation occurs by bursts of gliding dislocations on the slip systems with the
38 maximum resolved shear stresses. Both the yield stress and apparent strain hardening rate
39 increase strongly with decreasing column diameter and are not strongly influenced by the
40 number of active slip systems. The density of dislocations required to account for the
41 observed stresses by Taylor hardening are unrealistically high. Also, it seems unlikely that the
42 Ga damaged surface layer created in these columns during fabrication will have the strength
43 to block dislocation motion at the stresses observed here. Thus, it is concluded that the most
44 likely explanation for the observed dependence of the mechanical behaviour on column
45 diameter is that deformation is controlled by the activation of dislocation sources. As the
46 column size is decreased or as the plastic strain is increased, dislocations are lost through the
47 sample surface and the dislocation density is decreased. The decrease in dislocation density
48 results in an increase in the applied stress necessary for further plasticity by dislocation source
49 activation and is proposed to account for the observed yield stress and strain hardening
50 behaviour.
51
52
53
54

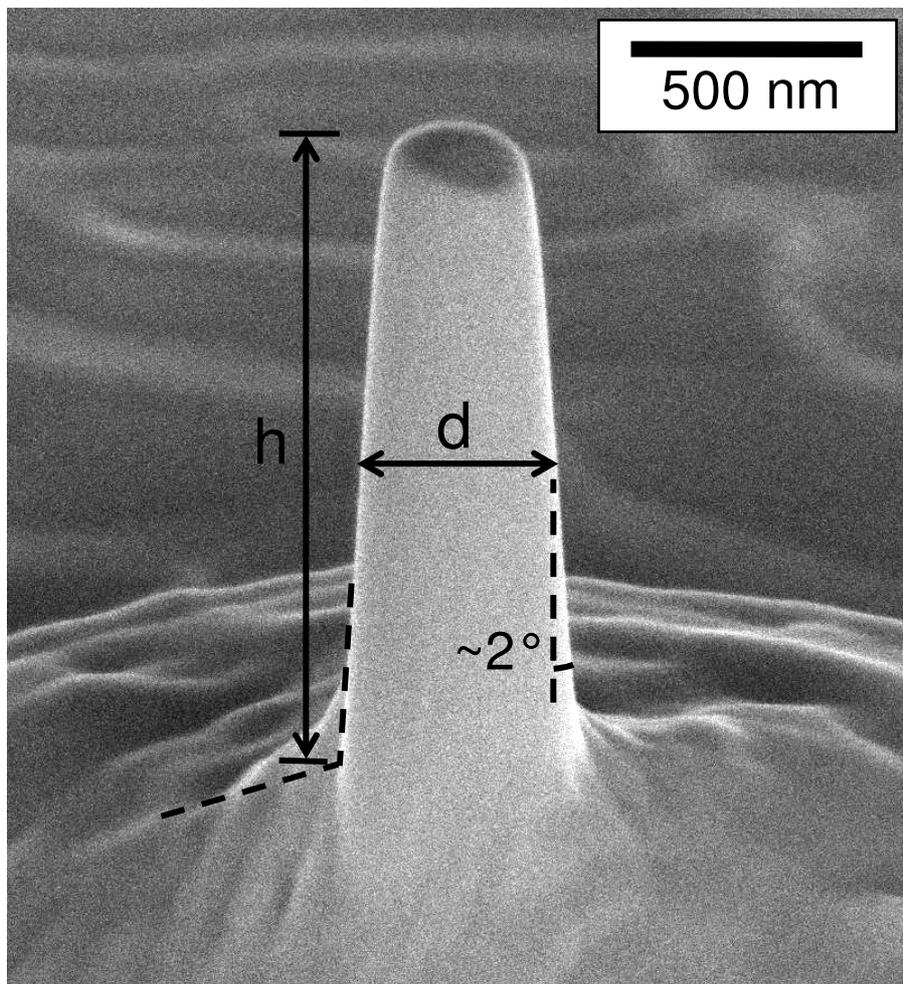
55 ACKNOWLEDGEMENTS

56 One of us (ETL) gratefully acknowledges support from the Alexander von Humboldt
57 Foundation.
58

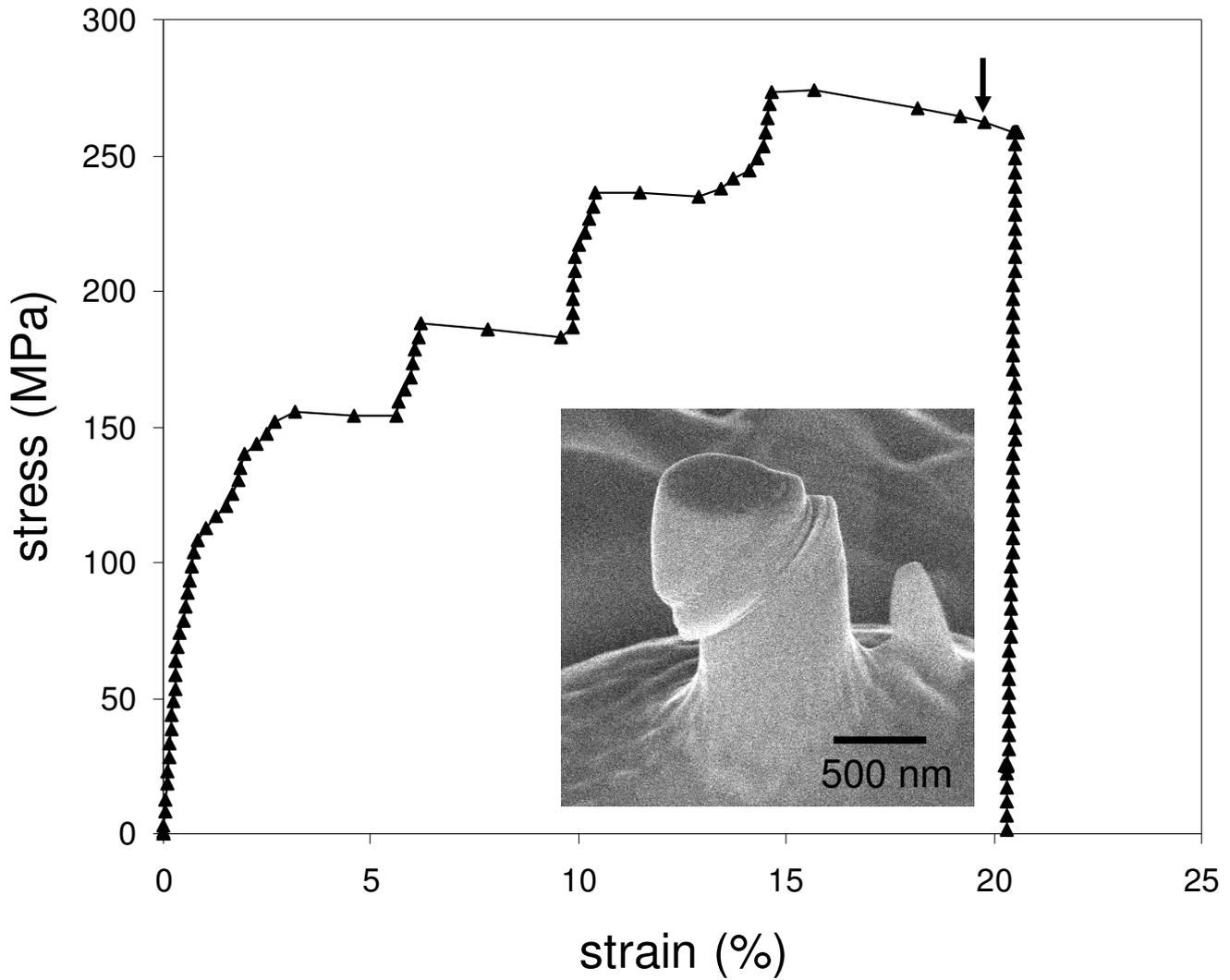
59 REFERENCES

60

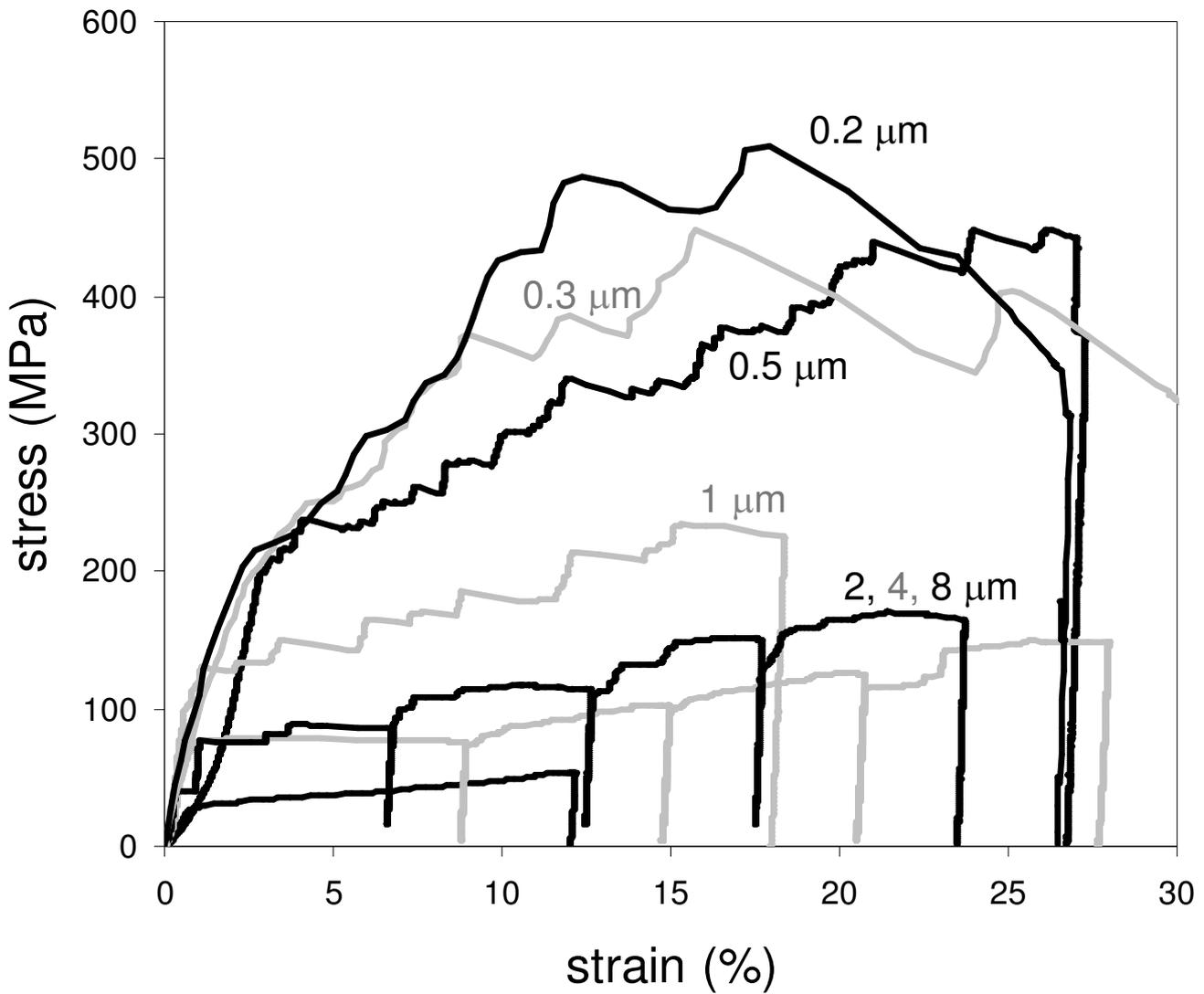
Volkert - Figure 1



Volkert - Figure 2



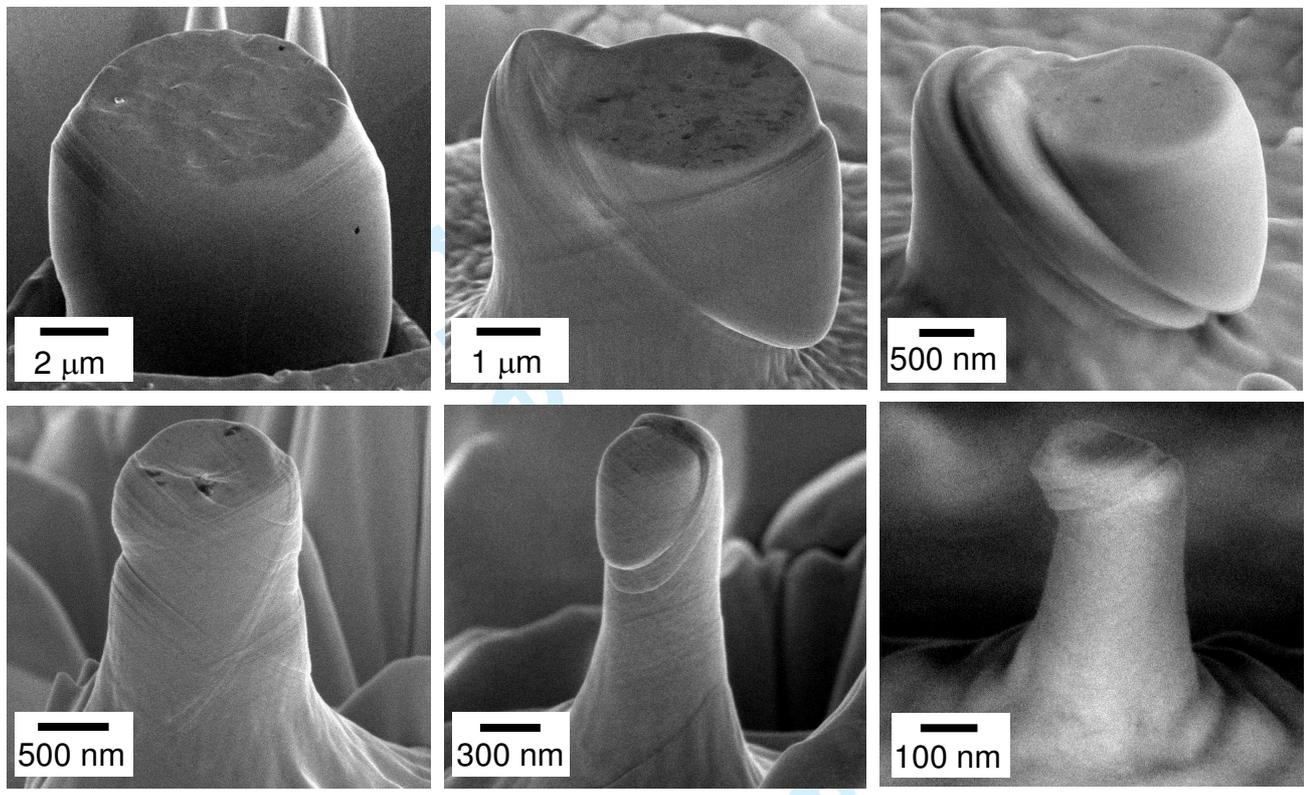
Volkert - Figure 3



only

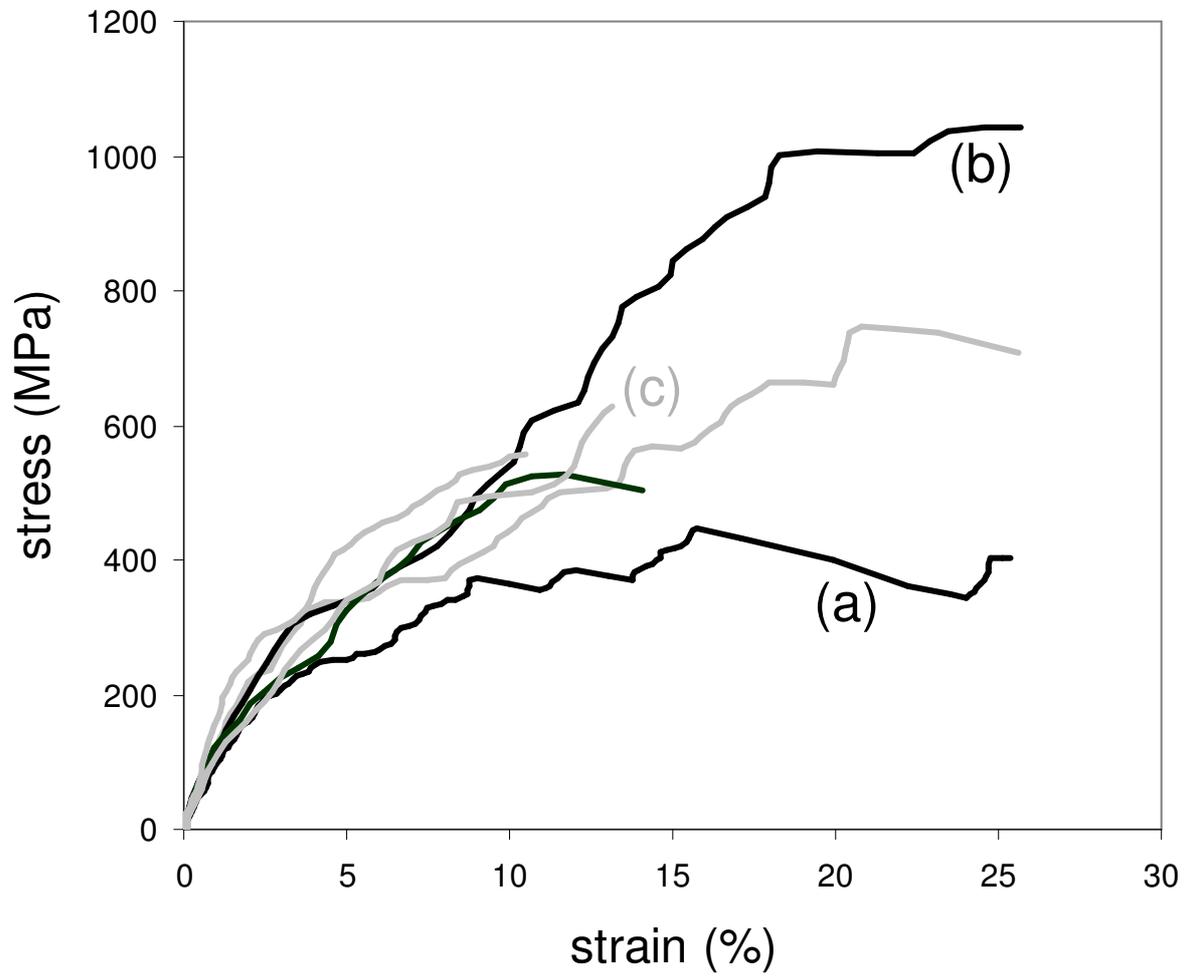
1
2
3
4
5
6
7
8
9
10
11
12
13
14
15
16
17
18
19
20
21
22
23
24
25
26
27
28
29
30
31
32
33
34
35
36
37
38
39
40
41
42
43
44
45
46
47
48
49
50
51
52
53
54
55
56
57
58
59
60

Volkert - Figure 4



Pre-proof Only

Volkert - Figure 5



Only

Volkert - Figure 6

